NSN 5961-01-107-9023

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-107-9023 **Inclosure Material:** Metal **Overall Length:** 1.437 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.682 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1300.00 reverse voltage, peak and 1.25 forward voltage, peak **Current Rating Per Characteristic:** 70.00 amperes forward current, average absolute and 1200.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: